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8 Vcc

10 🛛 NC

9

8

7

6

βg

18ľ

16

15

S

17

1 20 19

10 11 12 13

- No internal connection

TL7705BM ... FK PACKAGE

(TOP VIEW)

h v_{cc}

SENSE

RESET

RESET

NC

NC

NC 14

SENSE

RESET

7

5

SENSE

RESET

6 RESET

TL77xxBC ... D OR P PACKAGE

TL7705BM ... JG PACKAGE TL7705BQ ... D PACKAGE

(TOP VIEW)

TL7705BM . . . U PACKAGE

(TOP VIEW)

2

• 1

2

3

4

5

R S

RFF

СТП 3

GND [4

NC

REF

RESIN [

GND

NC

NC

CT Π7

NC Π8

5

NC - No internal connection

Π6

RESIN

CT [

RESIN

- **Power-On Reset Generator**
- **Automatic Reset Generation After** Voltage Drop
- **RESET** Output Defined From $V_{CC} \ge 1 V$
- **Precision Voltage Sensor**
- **Temperature-Compensated Voltage** Reference
- **True and Complement Reset Outputs**
- **Externally Adjustable Pulse Duration**

description

The TL7702B and TL7705B are integrated-circuit supply-voltage supervisors designed for use as reset controllers in microcomputer and microprocessor systems. The supply-voltage supervisor monitors the supply for undervoltage conditions at the SENSE input. During power up, the RESET output becomes active (low) when V_{CC} attains a value approaching 1 V. As V_{CC} approaches 3 V (assuming that SENSE is above V_{T+}), the delay timer function activates a time delay, after which outputs RESET and RESET go inactive (high and low, respectively). When an undervoltage condition occurs during normal operation, outputs **RESET** and **RESET** go active. To ensure that a complete reset occurs, the reset outputs remain active for a time delay after the voltage at the SENSE input exceeds the positive-going threshold value. The time delay is determined by the value of the external capacitor C_T: $t_d \approx 2.6 \times 10^4 \times C_T$, where C_T is in farads (F) and t_d is in seconds (s).

An external capacitor (typically 0.1 µF) must be connected to REF to reduce the influence of fast transients in the supply voltage.

The TL7702BC and TL7705BC are characterized for operation from 0°C to 70°C. The TL7702BI and TL7705BI are characterized for operation from -40°C to 85°C. The TL7705BQ is characterized for operation from -40°C to 125°C. The TL7705BM is characterized for operation from -55°C to 125°C.



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AVAILABLE OPTIONS											
		PA	CKAGED DEVIC	ES							
TA	SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLATPACK (U)	CHIP FORM (Y)					
0°C to 70°C	TL7702BCD	—	—	TL7702BCP	—						
0010700	TL7705BCD	—	—	TL7705BCP	—						
-40°C to 85°C	TL7702BID	—	—	TL7702BIP	—	TL7702BY,					
-40°C 10 85°C	TL7705BID	—	—	TL7705BIP	—	TL7705BY					
–40°C to 125°C	TL7705BQD	—	—	—	—						
–55°C to 125°C	—	TL7702BMFK	TL7702BMJG	_	TL7702BMU						
-55 C 10 125 C	_	TL7705BMFK	TL7705BMJG		TL7705BMU						

The D package is available taped and reeled. Add the suffix R to device type (e.g., TL7702BCDR). Chip forms are tested at 25° C.

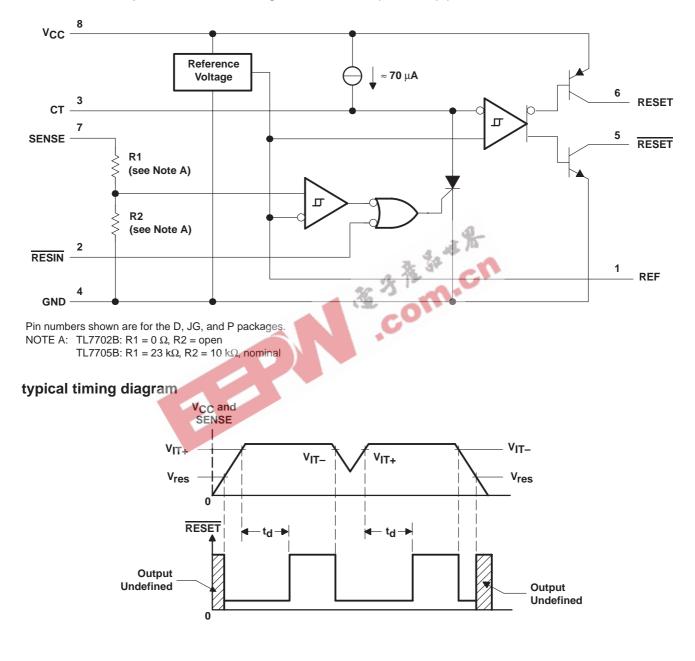




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functional block diagram

The functional block diagram is shown for illustrative purposes only; the actual circuit includes a trimming network to adjust the reference voltage and sense-comparator trip point.





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC} (see Note 1)	20 V
Input voltage range, VI: RESIN	
SENSE	–0.3 V to 20 V
High-level output current, I _{OH} (RESET)	
Low-level output current, I _{OL} (RESET)	
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D package	
P package	
Case temperature for 60 seconds, T _C : FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG or U packages	300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or P packages	260°C
Storage temperature range, T _{stg}	–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to the network ground terminal.

2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.

The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero. 3.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V _{CC}		3.6	18	V
High-level input voltage, VIH	RESIN	2	18	V
Low-level input voltage, VIL	RESIN	0	0.8	V
Input voltage, VI	SENSE	0	18	V
High-level output current, IOH	RESET		-16	mA
Low-level output current, IOL	RESET		16	mA
	TL770xBC	0	70	
Operating free-air temperature range, TA	TL770xBI	-40	85	°C
	TL7705BQ	-40	125	U
	TL7705BM	-55	125	



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electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS [†]	TL77xxBC TL77xxBI TL7705BQ			UNIT		
					MIN	TYP	MAX	
VOH	High-level output ve	oltage, RES	ET	I _{OH} = -16 mA	V _{CC} -1.5			V
VOL	Low-level output vo	oltage, RES	ET	I _{OL} = 16 mA			0.4	V
Vref	Reference voltage			$I_{ref} = 500 \ \mu A$, $T_A = 25^{\circ}C$	2.48	2.53	2.58	V
			TL7702B	T. 05%C	2.505	2.53	2.555	
N/	Negative-going VIT- input threshold voltage at SENSE input	TL7705B	$T_A = 25^{\circ}C$	4.5	4.55	4.6	v	
VIT-		age	TL7702B	- <i>(</i> u +	2.48	2.53	2.58	v
			TL7705B	T _A = full range [‡]	4.45	4.55	4.65	
. V.	Hysteresis, SENSE		TL7702B	$V_{CC} = 3.6 \text{ V to } 18 \text{ V}, \qquad T_{A} = 25^{\circ}\text{C}$		10		mV
V _{hys}	$(V_{IT+} - V_{IT-})$		TL7705B			30		mv
Vres§	Power-up reset vol	tage		I_{OL} at $\overline{RESET} = 2 \text{ mA}$, $T_A = 25^{\circ}C$			1	V
	Innut ourrent	RESIN		$V_{I} = 0.4 V \text{ to } V_{CC}$			-10	A
1	Input current	SENSE	TL7702B	VI = V _{ref} to 18 V		-0.1	-2	μA
ЮН	High-level output c	-level output current, RESET		V _O = 18 V, See Figure 1			50	μA
IOL	Low-level output current, RESET		ΞT	V _O = 0 V, See Figure 1			-50	μA
	Supply ourroat			$V_{SENSE} = 15 V, RESIN \ge 2 V$		1.8	3	mA
lcc	Supply current			$V_{CC} = 18 \text{ V},$ $T_A = \text{full range}^{\ddagger}$			3.5	mA

[†] All electrical characteristics are measured with 0.1-μF capacitors connected at REF, CT, and V_{CC} to GND. [‡] Full range is 0°C to 70°C for the C-suffix devices, -40°C to 85°C for the I-suffix devices, and -40°C to 125°C for the Q-suffix device. § This is the lowest voltage at which RESET becomes active.

switching characteristics, V_{CC} = 5 V, CT open, T_A = 25°C

PARAMETER		PARAMETER FROM TO (INPUT) (OUTPUT)		TEST CONDITIONS	TL77xxBC TL77xxBI TL7705BQ			UNIT
					MIN	TYP	MAX	
^t PLH	Propagation delay time from low- to high-level output	RESIN	RESET	See Figures 1. 2. and 2		270	500	ns
^t PHL	Propagation delay time from high- to low-level output	RESIN	RESET	See Figures 1, 2, and 3		270	500	ns
	Effective pulse duration	RESIN		See Figure 2		150		
tw	Effective pulse duration	SENSE				100		ns
tr	Rise time		DECET				75	ns
t _f	Fall time		RESET			150	200	115
tr	Rise time		RESET	See Figures 1 and 3		75	150	
tf	Fall time		RESET				50	ns



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electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAME	TED			t	TL7	705BM		UNIT
	PARAME	IER		TEST CON	DITIONS	MIN	TYP	MAX 0.4 2.58 2.555 4.6 2.58	UNIT
Vон	High-level output vo	oltage, RES	SET	I _{OH} = -16 mA		V _{CC} -1.5			V
VOL	Low-level output vo	oltage, RES	ET	I _{OL} = 16 mA				0.4	V
V _{ref}	Reference voltage			I _{ref} = 500 μA,	$T_A = 25^{\circ}C$	2.48	2.53	2.58	V
			TL7702B	T. 25%C		2.505	2.53	2.555	
\/	Negative-going		TL7705B	$T_A = 25^{\circ}C$		4.5	4.55	4.6	v
VIT-	input threshold voltage at SENSE input		TL7702B	$T_{A} = -55^{\circ}C$ to 125°C	2.48	2.53	2.58	v	
			TL7705B			4.45	4.55	4.65	
<u>۱</u>	Hysteresis, SENSE		TL7702B		T. 05%C		10		mV
V _{hys}	$(V_{IT+} - V_{IT-})$		TL7705B	$v_{\rm CC} = 3.6 \ v \ 10 \ 18 \ v,$	$V_{CC} = 3.6 V \text{ to } 18 V, \qquad T_A = 25^{\circ}C$		30		mv
v _{res} ‡	Power-up reset volt	tage		I _{OL} at RESET = 2 mA	, T _A = 25°C			1	V
	land a summary	RESIN		$V_{I} = 0.4 V$ to V_{CC}				-10	
łį	Input current	SENSE	TL7702B	$V_{I} = V_{ref}$ to $V_{CC} - 1.5$	V		-0.1	-2	μA
ЮН	High-level output co	urrent, RES	ET	V _O = 18 V	ß			50	μA
IOL	Low-level output cu	vel output current, RESET		VO = 0	Th			-50	μA
	Supply current			V _{SENSE} = 15 V,	RESIN ≥ 2 V	2	1.8	3	
ICC				V _{CC} = 18 V,	T _A			4	mA

[†] All electrical characteristics are measured with 0.1- μ F capacitors connected at REF, CT, and V_{CC} to GND. [‡] This is the lowest value at which RESET becomes active.

switching characteristics, $V_{CC} = 5 V$, CT open, $T_A = 25^{\circ}C$

	PARAMETER FROM		то	TEST CONDITIONS	TL7705BM			UNIT	
	PARAMETER	(INPUT)	(OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
^t PLH	Propagation delay time from low- to high-level output	RESIN	RESET			270	500*	ns	
^t PHL	Propagation delay time from high- to low-level output	RESIN	RESET	See Figures 1, 2, and 3		270	500*	ns	
	Effective pulse duration	RESIN				150			
tw		Ellective pulse duration		SENSE		See Figure 2		100	
tr	Rise time		DEOFT				75*		
tf	Fall time		RESET	See Figures 1 and 2		150	200*	ns	
t _r	Rise time		RESET	See Figures 1 and 3		75	150*	200	
tf	Fall time		RESET				50*	ns	

* On products compliant to MIL-PRF-38535, these parameters are not production tested.



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electrical characteristics over recommended operating conditions, $T_A = 25^{\circ}C$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS [†]	TL7702BY TL7705BY			UNIT		
					MIN	TYP	MAX		
Vон	High-level output voltage, RE	SET		I _{OH} = -16 mA	V _{CC} -1.5			V	
VOL	Low-level output voltage, RE	SET		I _{OL} = 16 mA			0.4	V	
V _{ref}	Reference voltage			I _{ref} = 500 μA	2.48	2.53	2.58	V	
\/. 	Negative-going input threshold voltage		TL7702BY		2.505	2.53	2.555	V	
VIT-	VIT- at SENSE input	at SENSE input		TL7705BY		4.5	4.55	4.6	V
			TL7702BY			10		mV	
V _{hys}	Hysteresis, SENSE (V _{IT+} – V	/IT_)	TL7705BY	$V_{CC} = 3.6 V \text{ to } 18 V$		30		mv	
V _{res} ‡	Power-up reset voltage			I _{OL} at RESET = 2 mA			1	V	
1.	loout ourroat	RESIN		$V_{I} = 0.4 V \text{ to } V_{CC}$			-10	A	
1	Input current	SENSE	TL7702BY	V _I = V _{ref} to 18 V		-0.1	-2	μA	
ЮН	IOH High-level output current, RESET		V _O = 18 V, See Figure 1			50	μA		
IOL	IOL Low-level output current, RESET		V _O = 0 V, See Figure 1			-50	μA		
ICC	Supply current			VSENSE = 15 V, RESIN \ge 2 V		1.8	3	mA	

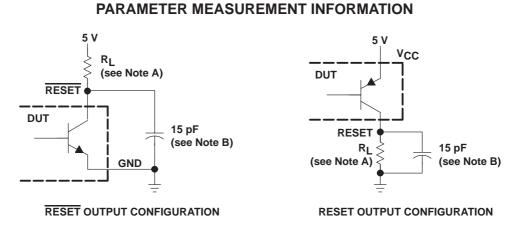
[†] All electrical characteristics are measured with 0.1- μ F capacitors connected at REF, CT, and V_{CC} to GND. [‡] This is the lowest voltage at which RESET becomes active.

switching characteristics, $V_{CC} = 5 V$, CT open, $T_A = 25^{\circ}C$

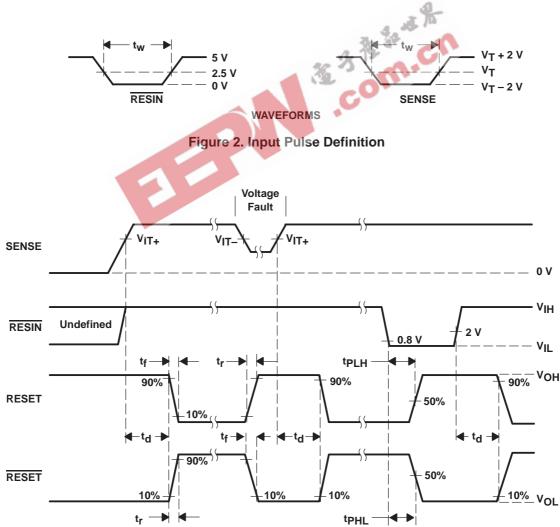
PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TL7702BY TL7705BY			UNIT
			(001101)		MIN	TYP	MAX	
^t PLH	Propagation delay time from low- to high-level output	RESIN	RESET	See Figures 1, 2, and 2		270	500	ns
tPHL	Propagation delay time from high- to low-level output	RÉSIN	RESET	See Figures 1, 2, and 3		270	500	ns
		RESIN		Coo Figuro 2		150		
tw	Effective pulse duration	SENSE		See Figure 2		100		ns
tr	Rise time		DEOET				75	ns
t _f	Fall time		RESET	See Figures 1 and 3		150	200	115
tr	Rise time		RESET	See Figures 1 and 5		75	150	ns
tf	Fall time		RESET				50	115



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NOTES: A. For I_{OL} and I_{OH}, R_L = 10 k Ω . For all switching characteristics, R_L = 511 Ω . B. This figure includes jig and probe capacitance.

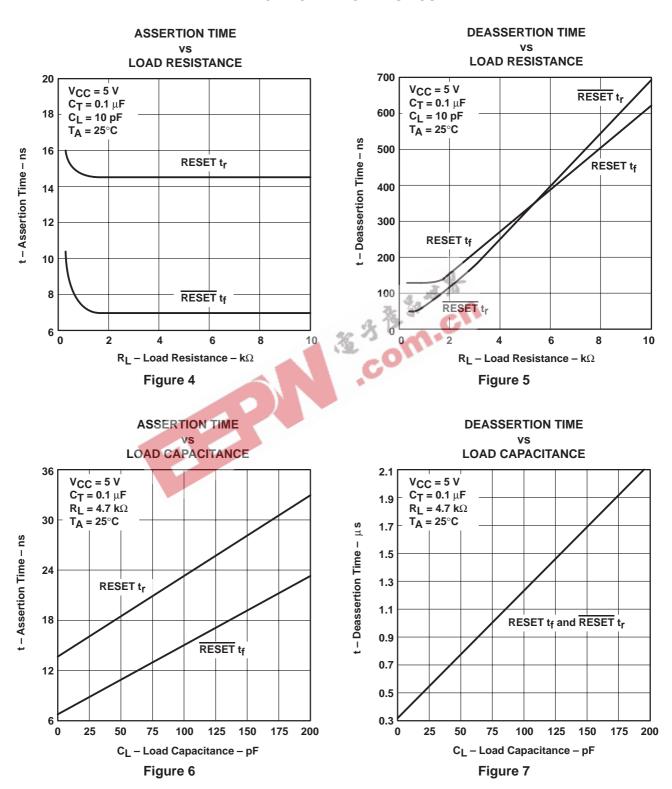








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TYPICAL CHARACTERISTICS[†]

[†] For proper operation, both RESET and RESET should be terminated with resistors of similar value. Failure to do so may cause unwanted plateauing in either output waveform during switching.

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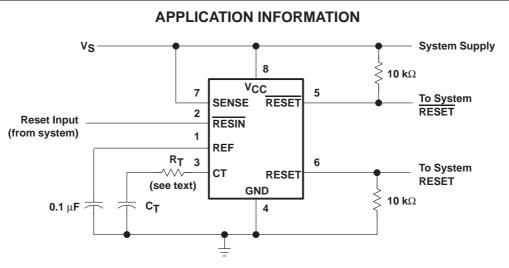


Figure 8. System Reset Controller With Undervoltage Sensing

When the TL770xB SENSE terminal is used to monitor V_{CC} , a current-limiting resistor in series with C_T is recommended. During normal operation, the timing capacitor is charged by the onboard current source to approximately V_{CC} or an internal voltage clamp (\approx 7.1-V zener), whichever is less. When the circuit is then subjected to an undervoltage condition during which V_{CC} is rapidly slewed down, the voltage on CT exceeds that on V_{CC} . This forward biases a secondary path internally, which falsely activates the outputs. A fault is indicated when V_{CC} drops below $V_{(CT)}$, not when V_{SENSE} falls below V_{T-} .

Texas Instruments performs a 100% electrical screen to verify that the outputs do not switch with 1 mA forced into the CT terminal. Adding the external resistor, R_T, prevents false triggering. Its value is calculated as follows:

$$\frac{V_{(CT)}-V_{T_{-}}}{R_{T}}$$

Where:

 $V_{(CT)} = V_{CC}$ or 7.1 V, whichever is less $V_{T-} = 4.55$ V (nom) $R_T =$ value of series resistor required

For $V_{CC} = 5$ V:

$$\frac{5-4.55}{R_{T}}$$
 < 1 mA

Therefore,

 R_{T} > 450 Ω

Using a 20% tolerance resistor, R_T should be greater than 560 Ω .

Adding this series resistor changes the duration of the reset pulse by no more than 10%. R_T extends the discharge of C_T , but also skews the $V_{(CT)}$ threshold. These effects tend to cancel one another. The precise percentage change can be derived theoretically, but the equation is complicated by this interaction and is dependent upon the duration of the supply-voltage fault condition.

Both outputs of the TL770xB should be terminated with similar value resistors, even when only one is being used. This prevents unwanted plateauing in either output waveform during switching, which may be interpreted as an undefined state or delay system reset.



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